

Bound states of ^3He at the edge of a ^4He drop on a cesium surface

R. Mayol,¹ M. Barranco,¹ E.S. Hernández,² M. Pi,¹ and M. Guilleumas¹

¹*Departament ECM, Facultat de Física, Universitat de Barcelona, E-08028 Barcelona, Spain*

²*Departamento de Física, Facultad de Ciencias Exactas y Naturales, Universidad de Buenos Aires, 1428 Buenos Aires, Argentina*

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Abstract

We show that small amounts of ^3He atoms, added to a ^4He drop deposited on a flat cesium surface at zero temperature, populate bound states localized at the contact line. These edge states show up for drops large enough to develop well defined surface and bulk regions together with a contact line, and they are structurally different from the well-known Andreev states that appear at the free surface and at the liquid-solid interface of films. We illustrate the one-body density of ^3He in a drop with 1000 ^4He atoms, and show that for sufficiently large number of impurities, the density profiles spread beyond the edge, coating both the curved drop surface and its flat base and eventually isolating it from the substrate.

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During the last decade, experimental and theoretical studies of wetting phenomena on substrates of various adsorptive strenghts have considerably enriched the physics of quantum fluids. Liquid ^4He , which was early believed to be a universal wetting agent, exhibits finite wetting temperatures on cesium surfaces [1]. On the other hand, the theoretical prediction that ^3He is a universal wetting agent [2] was confirmed by measurements of its adsorption isotherms on Cs [3]. These opposite and complementary wetting properties combine in a very interesting manner when the helium isotopes coexist in a low-temperature solution, since ^3He dissolved into bulk liquid or ^4He films populates a two-dimensional homogeneous layer of Andreev states on the free surface (see e.g., Ref. [4] and refs. therein).

Andreev-like states for a single ^3He atom, localized at the liquid-substrate interface of a ^4He film on a variety of adsorbers, including weak alkalis like Cs, were predicted within the frame of density functional (DF) theory [5]. The effect of ^3He impurities on the liquid-vapor and liquid-solid surface tensions of ^4He on Cs is a key ingredient in the prediction of reentrant wetting by helium mixtures [6], as measured shortly afterwards [7,8]. The existence of the interfacial bound states was confirmed by experimental evidence [9] and by microscopic variational calculations [10]. More recent measurements of the contact angle of helium mixtures on Cs [11] showed that the large observed values are consistent with both single-particle (sp) states of the ^3He atoms at the liquid-solid interface and surface excitations.

The preference of ^3He to migrate to the surface of ^4He is a very general consequence of the mutual interaction between the isotopes, and this structure appears as well in density profiles of mixed drops as described by DF theory [12–14]. These descriptions of finite helium mixtures consider freely standing systems in vacuum; however, mixed clusters deposited on adsorbing substrates offer an interesting illustration of the competition between selfsaturation, mutual interaction between the helium isotopes and external confinement, with consequences on their wetting behavior. A theoretical approach has been anticipated for droplets of pure ^4He on Cs, whose profiles and contact angles have been recently computed [15], employing a Finite Range Density Functional (FRDF) [16] at zero temperature.

In this letter, we present DF calculations of nanoscale mixed ^3He - ^4He droplets at zero temperature on a flat Cs surface using the FRDF for mixtures of Ref. [17] and demonstrate that the lowest-lying ^3He sp bound states are localized on the perimeter of the ^4He base -i.e., the contact line. These are genuine edge states of a different nature than the well-known Andreev ones, since they originate in the peculiarities of the mean field for this specific geometry.

For this sake, assuming axial symmetry around the z -axis perpendicular to the Cs substrate, by functional differentiation of the energy density we derive the Euler-Lagrange (EL) equation for the ^4He particle density $\rho_4(r, z)$ and the Kohn-Sham (KS) equations for the ^3He sp wave functions (wf's) $\psi_{nl}(r, z)e^{il\varphi}$, with l the z -projection of the orbital angular momentum, for fixed particle numbers N_i ($i=3, 4$). The general form of these equations can be found in Ref. [13]; hereafter we shall mostly restrict our considerations to the case $N_4 = 1000$ and varying N_3 as discussed below.

The first problem that we solve is the Schrödinger equation for one ^3He atom in the field of a ^4He cluster on a Cs surface, with the Cs-He potential of Ref. [15]. In Fig. 1 we show contour plots on the $y = 0$ plane (hereafter, lengths are given in Å) of the probability densities $|\psi_{n0}(r, z)|^2$ for $n = 1, 2$, and 3, together with grayscale views of the density $\rho_4(r, z)$, which exhibits the layered structure encountered in films on flat surfaces [18] (see also Ref. [15]).

The most spectacular result is undoubtedly the appearance of the $1s$ ground state (gs) ψ_{10} , since the sharp localization of the impurity on the contact line indicates the existence of a new kind of sp state, the edge state. With a truly one-dimensional (1D) probability density on a ring of mesoscopic size, it would certainly exist in a macroscopic droplet, being in essence a 1D analog of the two-dimensional Andreev state at the planar free surface of ^4He . Its origin is the density distribution of the ^4He drop, that together with the potential created by the substrate, gives rise to the strong attraction experienced by the impurity near the contact line. In addition, the enhanced surface width of the ^4He cluster at the edge, due to the overlapping spreads of both the upper and the lower surface, permits large zero point

motion of the impurity, thus lowering its kinetic energy and favouring binding.

We display in Fig. 2 the evolution of the sp energy ε_{1s} with N_4 , which shows that for relatively small sizes (around $N_4=2000$), the curve seems to be asymptotic to a certain value, the macroscopic limit. We have verified as well that s -states with n between 2 and 8 span an energy shell, with a width of about 1.3 K starting at $\varepsilon_{20}=-4.74$ K, for i.e., $N_4 = 1000$ (cf. Fig. 3), that could be regarded as fragmentation of the Andreev state of the free surface of films, induced by finite size and curved shape. This is supported by the shape of the excited probability densities displayed in Fig. 1, which display peaks on the upper surface of the drop.

Noticeably also, we have found that the probability densities $|\psi_{1l}(r, z)|^2$ for $l > 0$ are essentially identical to $|\psi_{10}(r, z)|^2$. This reflects the fact that these excitations consist of rotations of the gs ψ_{10} around the symmetry axis of the ^4He drop, as can be seen in the sp level scheme depicted in Fig. 3. Instead, since s -excited states possess nonvanishing probability density on the rotational axis, states with $n > 1$ and $l > 0$ are more sensitive to the centrifugal potential, that splits the cusp creating extra lobes in the higher levels described by wf's $\psi_{nl}(r, z)$.

For the rotational band, the sp energies follow the rule

$$\varepsilon_{1l} = \varepsilon_{10} + \frac{\hbar^2 l^2}{2m_{10}^* R_{10}^2} \quad (1)$$

with $\varepsilon_{10} = -5.03$ K. Effective masses m_{nl}^* , defined as the state averages of the local, density-dependent one [5],

$$\frac{1}{m_{nl}^*} = \int d\vec{r} \frac{1}{m_3^* [\rho_4(r, z)]} [\psi_{nl}(r, z)]^2 \quad (2)$$

are parameters that appear naturally in the prefactor of the centrifugal potential as one computes the expectation value of the sp hamiltonian. In this case, we obtain $m_{10}^* = 1.21 m_3$, which together with the slope of the linear regression in Fig. 3 gives a gs radius $R_{10} = 35.1$ Å. We point out that if $m_{10}^* = m_3$, the corresponding values $\varepsilon_{10} = -4.86$ K and $R_{10} = 34.7$ Å reveal the scarce relevance of this parameter to our main results. For the s -states

$n=2$ to 8, the respective m_{n0}^* are similar and close to $1.3 m_3$, that scales with the effective mass for the Andreev surface state in ^4He films on Cs [6,10,19], around $1.45 m_3$.

As a second step, we have solved the system consisting of the coupled EL/KS equations, for N_3 values corresponding to closed shell configurations made of sp states within the gs rotational band. For small N_3 values, the level filling sequence still corresponds to the sp spectrum of a single atom, with slightly decreasing slopes of the gs rotational band, due to the finite ^3He density which enhances the effective mass, and smaller values of $|\varepsilon_{10}|$ also depending on N_3 . This is illustrated in Fig. 3 for $N_3 = 26$. The shape of the wf's $\psi_{1l}(r, z)$ below the Fermi sea is now sensitive to N_3 , and $\rho_4(r, z)$ is also affected; maps of the ^3He and ^4He particle densities, with details as in Fig. 1, are depicted in Fig. 4, showing the tendency of the ^3He density to drift upwards on the drop surface; note that the lowest ^3He density line corresponds to $10^{-6} \text{\AA}^{-3}$.

A substantial simplification of the above full coupled problem, within excellent accuracy for sufficiently large N_3 , is provided by the Thomas-Fermi (TF) method [20]. We apply this procedure to $N_3 \geq 100$, and find that at $N_3 = 100$, the density profile of the impurities covers the free surface of the ^4He drop, and tends to isolate it from the substrate. For N_3 between 100 and 150, the situation qualitatively changes, and ^3He spreads beyond the edge of the ^4He drop giving rise to a thin film of ^3He that coats the Cs substrate with an asymptotic coverage n_3 . As our interest here is in finite systems, we have just solved the problem of the splashed $^4\text{He}_{1000}$ droplet for two very low asymptotic coverages, namely $n_3 = 2 \times 10^{-3}$ and $3 \times 10^{-3} \text{\AA}^{-2}$.

Figure 5 is a three-dimensional view of $\rho_3(r, z)$ corresponding to $n_3 = 3 \times 10^{-3} \text{\AA}^{-2}$, where the occupied edge states of the single atoms can be visualized as large peaks near the contact line, while Fig. 6 exhibits the corresponding $\rho_4(r, z)$. The layering of the ^3He density appears as a series of peaks on the covering shell on the ^4He cluster; in addition, we note the spreading of $\rho_3(r, z)$ near the substrate as r increases beyond the region populated by the edge states. In this case, the number of ^3He atoms inside a cylinder of radius $R = 50 \text{\AA}$ is ~ 180 , and ~ 138 for $n_3 = 2 \times 10^{-3} \text{\AA}^{-2}$.

Finally, we comment on the contact angle, whose determination for nanoscopic droplets is far from trivial, as discussed in [15]. We have seen that helium droplet densities display non-negligible surface widths and are highly stratified near the substrate. This structure renders the contact angle an ill defined quantity, and one has to resort to methods such as that in [15], since a determination of the contact angle by ‘visual inspection’ of the equidensity lines may only lead to a rather crude estimate. For the pure ^4He droplets our results coincide with those of [15], thus the procedure there described would give a contact angle of about 30 degrees.

The presence of ^3He affects the contact angle, as can be judged from Fig. 7, where we show the contour plot of the total $^3\text{He}+^4\text{He}$ density corresponding to roughly half the bulk ^4He density for $N_4 = 1000$ and the above two ^3He coverages. It appears from this figure that whereas the height of the cap does not change visibly, the radius of the cap base increases by 8 – 10% and this should have a sizeable effect in any sensible determination of the contact angle.

To summarize, we have found that in addition to the well known Andreev states, ^4He drops on Cs substrates host a new class of ^3He sp states which appear as 1D rings of ^3He atoms surrounding the contact line for mesoscopic drops or wedges, and are the lowest-lying. The gs energies found in this work are, for the largest clusters, close to those of surface [5,19] Andreev states, around -5.1 K depending on the ^4He coverage, and below the interfacial [9,19] Andreev states, around -4.3 K. The experimental detection of these edge states might be a challenge, open to seeking thermodynamic evidence through specific heat or magnetic susceptibility measurements below the dewetting line of the low temperature phase diagram for mixtures [8], or dynamical evidence for undamped 1D spin-density oscillations [21]. The statistical model in Ref. [11] shows that the most likely scenario for measured contact angles and surface tensions must include both Andreev states and ripplons at the substrate-liquid interface; accordingly, it might be interesting to examine the effects of the new edge states -so far overlooked- in this description.

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FIGURES

FIG. 1. Probability densities of s -states of a ^3He atom together with the ^4He particle density in the $y = 0$ plane for a drop with $N_4=1000$.

FIG. 2. Energy of the $1s$ state for $N_4 = 20, 100, 500, 1000, 1500, 2000$, and 3000 . The calculated energy of one single ^3He atom on a Cs substrate is also given. The dotted line has been drawn as a to guide the eye.

FIG. 3. Spectrum of a single ^3He atom as a function of squared angular momentum for the bands $n = 1$ to 4 , together with the KS energies of the occupied sp levels corresponding to $N_3 = 26$ (open circles), with dotted lines to guide the eye.

FIG. 4. The EL/KS ^3He and ^4He particle densities for $N_3 = 26$ and $N_4 = 1000$.

FIG. 5. Threedimensional view of the ^3He particle density in the $y = 0$ plane for $N_4 = 1000$ and $n_3 = 3 \times 10^{-3} \text{\AA}^{-2}$. The highest density peaks correspond to $\rho_3 \sim 1.4 \times 10^{-2} \text{\AA}^{-3}$.

FIG. 6. Threedimensional view of the ^4He particle density in the $y = 0$ plane for $N_4 = 1000$ and $n_3 = 3 \times 10^{-3} \text{\AA}^{-2}$. The highest density ridge corresponds to $\rho_4 \sim 2.4 \times 10^{-2} \text{\AA}^{-3}$.

FIG. 7. Contour plots of the total $^3\text{He}+^4\text{He}$ density corresponding to $0.011 \text{\AA}^{-3}$ for the case $N_4 = 1000$ and $n_3 = 2 \times 10^{-3} \text{\AA}^{-2}$, $n_3 = 3 \times 10^{-3} \text{\AA}^{-2}$. The dashed line corresponds to the pure ^4He drop.

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